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# UPA811T

# NPN SILICON HIGH FREQUENCY TRANSISTOR

# **FEATURES**

- SMALL PACKAGE STYLE:
   2 NE680 Die in a 2 mm x 1.25 mm package
- LOW NOISE FIGURE:
   NF = 1.9 dB TYP at 2 GHz
- HIGH GAIN:  $|S_{21}E|^2 = 7.5 \text{ dB TYP at 2 GHz}$
- EXCELLENT LOW VOLTAGE, LOW CURRENT PERFORMANCE

## **DESCRIPTION**

The UPA811T is two NPN high frequency silicon epitaxial transistors encapsulated in an ultra small 6 pin SMT package. Each transistor is independently mounted and easily configured for either dual transistor or cascode operation. The high ft, low voltage bias and small size make this device ideally suited for pager and other hand-held wireless applications.

## ABSOLUTE MAXIMUM RATINGS<sup>1</sup> (TA = 25°C)

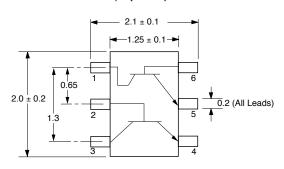
(M=20 0)							
SYMBOLS	PARAMETERS	UNITS	RATINGS				
Vсво	Collector to Base Voltage	V	20				
VCEO	Collector to Emitter Voltage	٧	10				
VEBO	Emitter to Base Voltage	V	1.5				
Ic	Collector Current	mA	35				
Рт	Total Power Dissipation 1 Die 2 Die	mW mW	110 200				
TJ	Junction Temperature	°C	150				
Тѕтс	Storage Temperature	°C	-65 to +150				

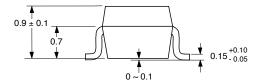
#### Note:

 Operation in excess of any one of these parameters may result in permanent damage.

# **OUTLINE DIMENSIONS** (Units in mm)

### PACKAGE OUTLINE S06 (Top View)





## PIN OUT

- 1. Collector Transistor 1
- 2. Base Transistor 2
- 3. Collector Transistor 2
- 4. Emitter Transistor 2
- 5. Emitter Transistor 1
- 6. Base Transistor 1

#### Note:

Pin 3 is identified with a circle on the bottom of the package.

# **ELECTRICAL CHARACTERISTICS** (TA = 25°C)

PART NUMBER PACKAGE OUTLINE			UPA811T S06		
SYMBOLS	PARAMETERS AND CONDITIONS	UNITS	MIN	TYP	MAX
Ісво	Collector Cutoff Current at VcB = 10 V, IE = 0	μΑ			1.0
ІЕВО	Emitter Cutoff Current at VEB = 1 V, IC = 0	μΑ			1.0
hFE <sup>1</sup>	Forward Current Gain at VCE = 3 V, IC = 5 mA		80	120	200
f⊤	Gain Bandwidth at VcE = 3 V, Ic = 5 mA	GHz	5.5	8.0	
Cre <sup>2</sup>	Feedback Capacitance at VcB = 3 V, IE = 0, f = 1 MHz	pF		0.3	0.7
IS <sub>21El</sub> <sup>2</sup>	Insertion Power Gain at VCE = 3 V, IC = 5 mA, f = 2 GHz	dB	5.5	7.5	
NF	Noise Figure at VcE = 3 V, Ic = 5 mA, f = 2 GHz	dB		1.9	3.2

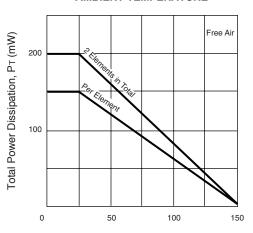
#### Notes:

- 1. Pulsed measurement, pulse width  $\leq$  350  $\mu$ s, duty cycle  $\leq$  2 %.
- 2. The emitter terminal should be connected to the ground terminal of the 3 terminal capacitance bridge.

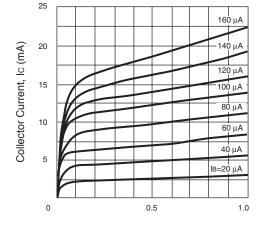
For Tape and Reel version use part number UPA811T-T1, 3K per reel.

# TYPICAL PERFORMANCE CURVES (TA = 25°C)

### TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



Ambient Temperature, Ta (°C)

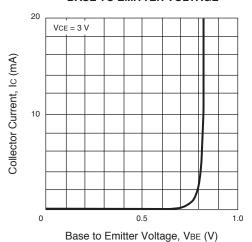


**COLLECTOR CURRENT vs.** 

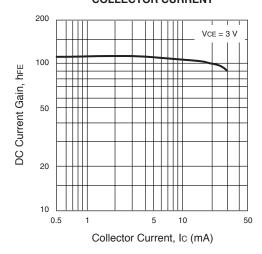
**COLLECTOR TO EMITTER VOLTAGE** 

Collector to Emitter Voltage, VCE (V)

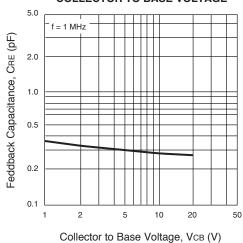
### **COLLECTOR CURRENT vs. BASE TO EMITTER VOLTAGE**



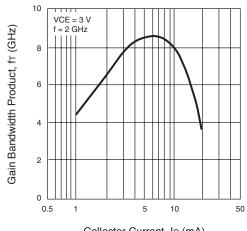
### DC CURRENT GAIN vs. **COLLECTOR CURRENT**



## FEEDBACK CAPACITANCE vs. **COLLECTOR TO BASE VOLTAGE**



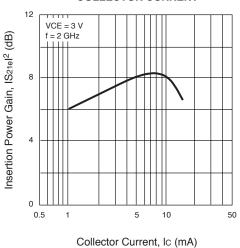
### GAIN BANDWIDTH PRODUCT vs. **COLLECTOR CURRENT**



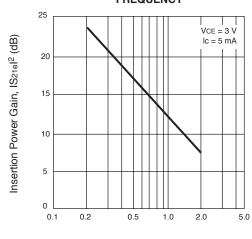
Collector Current, Ic (mA)

# TYPICAL PERFORMANCE CURVES (TA = 25°C)

# INSERTION POWER GAIN vs. COLLECTOR CURRENT

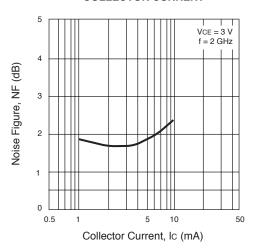


# INSERTION POWER GAIN vs. FREQUENCY



### Frequency, f (GHz)

# NOISE FIGURE vs. COLLECTOR CURRENT



# **ORDERING INFORMATION**

PART NUMBER	QUANTITY	PACKAGING				
UPA811T-T1-A	3000	Tape & Reel				